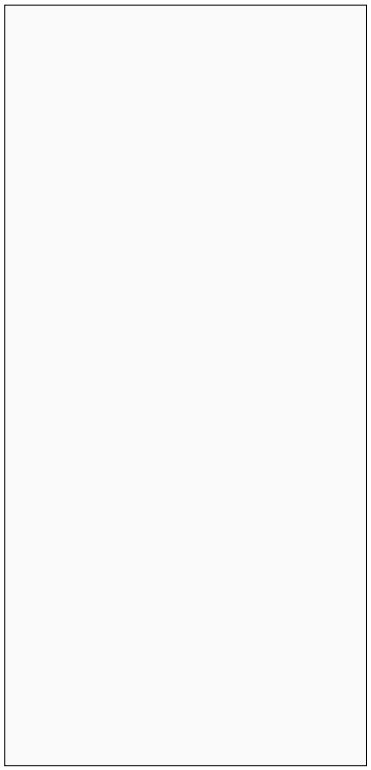
DESCRIPTION:

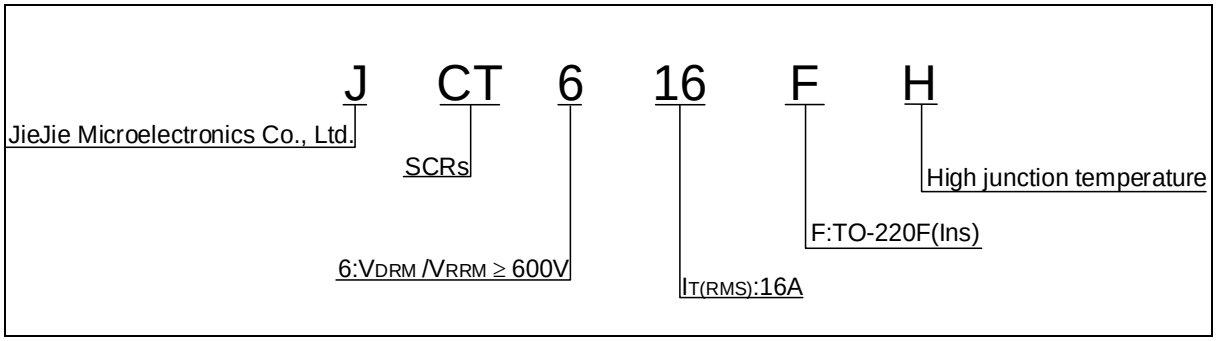
With high ability to withstand



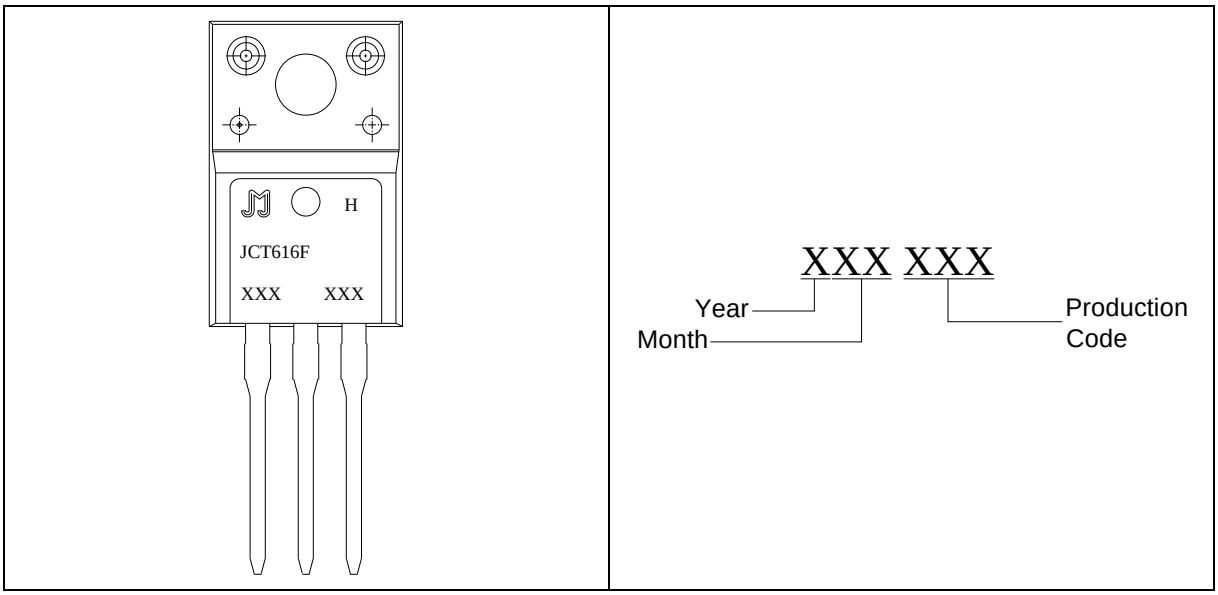
Average gate power dissipation (T_j=150)	$P_{G(AV)}$	1	W
Peak gate power	P_{GM}	20	W
Peak pulse voltage (T_j=25 ; non-repetitive,off-state;FIG.7)	V_{pp}	0.5	kV

[redacted]

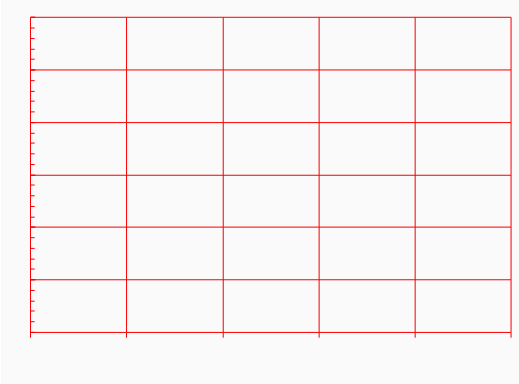
ORDERING INFORMATION



MARKING



Maximum power dissipation versus RMS on-state current



RMS on-state current versus case temperature

ORDERING INFORMATION

Date	Revision	Changes
Jun.15, 2023	A.1.0	Last update
Oct.17, 2022	Ǝ Ǥ0¾	⅄

PACKAGE MECHANICAL DATA